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Rib Data Sheet

CONFIRMATION NO. 1442

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|--|---|-----------------------------------|---|------------------|---|--|-----------------------|-------------------------------------|---------------------------------------|--|
| SERIAL NUMB 10/603,862 | ER | FILING DATE 06/26/2003 RULE | C | CLASS 716 | GROUP ART UNIT 2825 | | UNIT | ATTORNEY DOCKET NO. 239479US2 | | |
| APPLICANTS | | | | | | | | | | |
| Toshiki Kanamoto, Tokyo, JAPAN; | | | | | | | | | | |
| Hirokazu Ikeda, Tokyo, JAPAN; | | | | | | | | | | |
| ** CONTINUING DATA ********************************** | | | | | | | | | | |
| ** FOREIGN APPLICATIONS ************************************ | | | | | | | | | | |
| IF REQUIRED, FOREIGN FILING LICENSE GRANTED ** 09/02/2003 | | | | | | | | | | |
| Foreign Priority claimed 35 USC 119 (a-d) conditions met Verified and Acknowledged Yes no Met after Allowance NM Examiner's Signature Initials | | | | STATE OR | SHEETS | | ТОТ | OTAL INDEPENDEN | | |
| | | | | COUNTRY JAPAN | DRAWING 11 | | CLAIMS 6 | | CLAIMS 2 | |
| ADDRESS 22850 OBLON, SPIVAK, MCCLELLAND, MAIER & NEUSTADT, P.C. 1940 DUKE STREET ALEXANDRIA , VA 22314 | | | | | | | | | | |
| TITLE Parasitic capacitance extracting device and method for semiconductor integrated circuit | | | | | | | | | | |
| | | | | | | | ☐ All Fees | | | |
| FILING FEE | FEES: Authority has been given in P No to charge/credit DEF No for following: | | | aper | 1.16 Fees (Filing) | | | | | |
| RECEIVED 750 | | | | | ☐ 1.17 Fees (Processing Ext. of time) | | | | | |
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